TOSHIBA Transistor Silicon NPN Triple Diffused Type

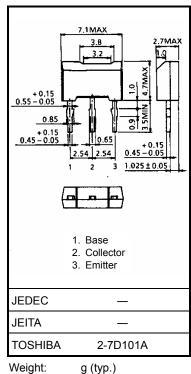
2SC6010

High Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

• High speed switching: $t_f = 0.24 \mu s \text{ (max)} (I_C = 0.3 \text{A})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	600	V	
Collector-emitter voltage		V _{CEX}	600	V	
Collector-emitter voltage		V _{CEO}	285	V	
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	Ι _C	1.0	А	
	Pulse	ICP	2.0		
Base current		Ι _Β	0.5	A	
Collector power dissipation	Ta = 25°C	P _C	1.0	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

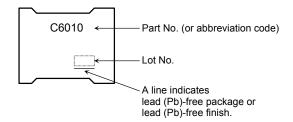
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

Electrical Characteristics (Ta = 25°C)

Chara	Characteristics Symbol Test Condition		Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	V _{CB} = 600 V, I _E = 0	_	—	100	μA
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	μA
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _B = 0	600	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	285	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA 80		—	200	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.1 A	100	_	200	
		h _{FE (3)}	V _{CE} = 5 V, I _C = 0.2 A	60	_	_	
Collector emitter saturation voltage		V _{CE (sat)}	I _C = 0.6 A, I _B = 75 mA		_	1.0	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 0.6 A, I _B = 75 mA		_	1.3	V
Rise time Switching time Fall time	Rise time	tr	20 µs V _{CC} ≈ 200 V	_	_	0.4	
	Storage time	t _{stg}			_	3.0	μs
	Fall time	tf	I _{B1} = 20 mA, −I _{B2} = 50 mA DUTY CYCLE ≤ 1%	_	_	0.24	

Marking



TOSHIBA

200

150

100

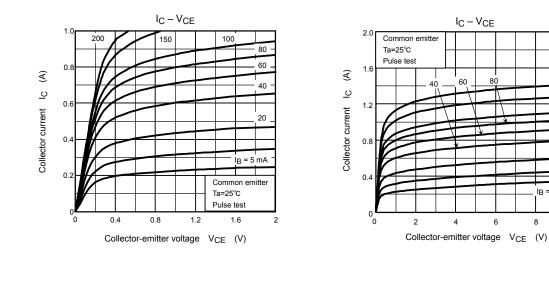
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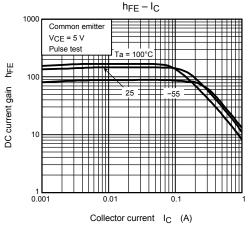
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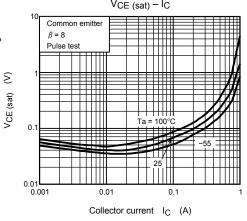
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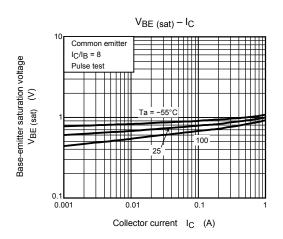
IB = 5 mA

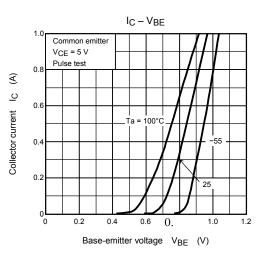
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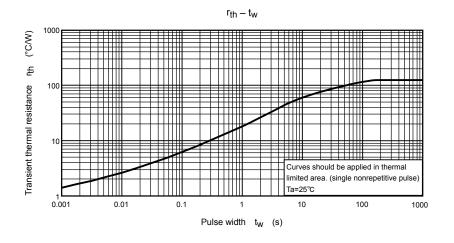


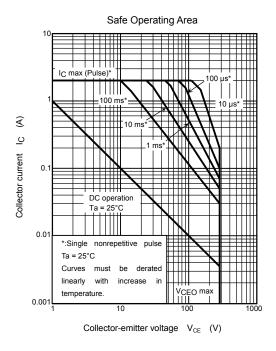




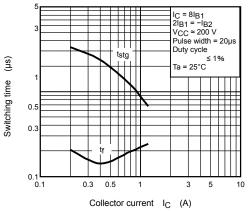
VCE (sat) - IC

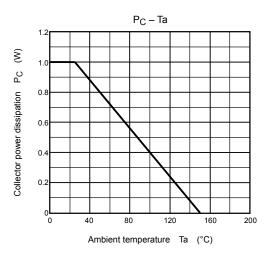
Collector-emitter saturation voltage





Switching Characteristics – I_C





RESTRICTIONS ON PRODUCT USE

20070701-EN

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